



1.54 inch E-paper Display Series



GDEP0150C1

Dalian Good Display Co., Ltd.



Revision History

Rev.	Issued Date	Revised Contents
1.0	Aug.14.2014	Preliminary
1.1	Sep.29.2014	Change the Module Name to GDEP015OC1
2.0	Feb.27.2017	In part 7-5: Modify Reference Circuit
2.1	Aug.04.2017	In part 7-5: Modify Reference Circuit
2.2	Oct.24.2018	In part 7-5: Modify Reference Circuit



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1. Over View

The display is a TFT active matrix electrophoretic display, with interface and a reference system design.

The 1.54inch active area contains 200×200 pixels, and has 1-bit full display capabilities. An integrated circuit contains gate buffer, source buffer, interface, timing control logic, oscillator, DC-DC. SRAM, LUT, VCOM, and border are supplied with each panel.

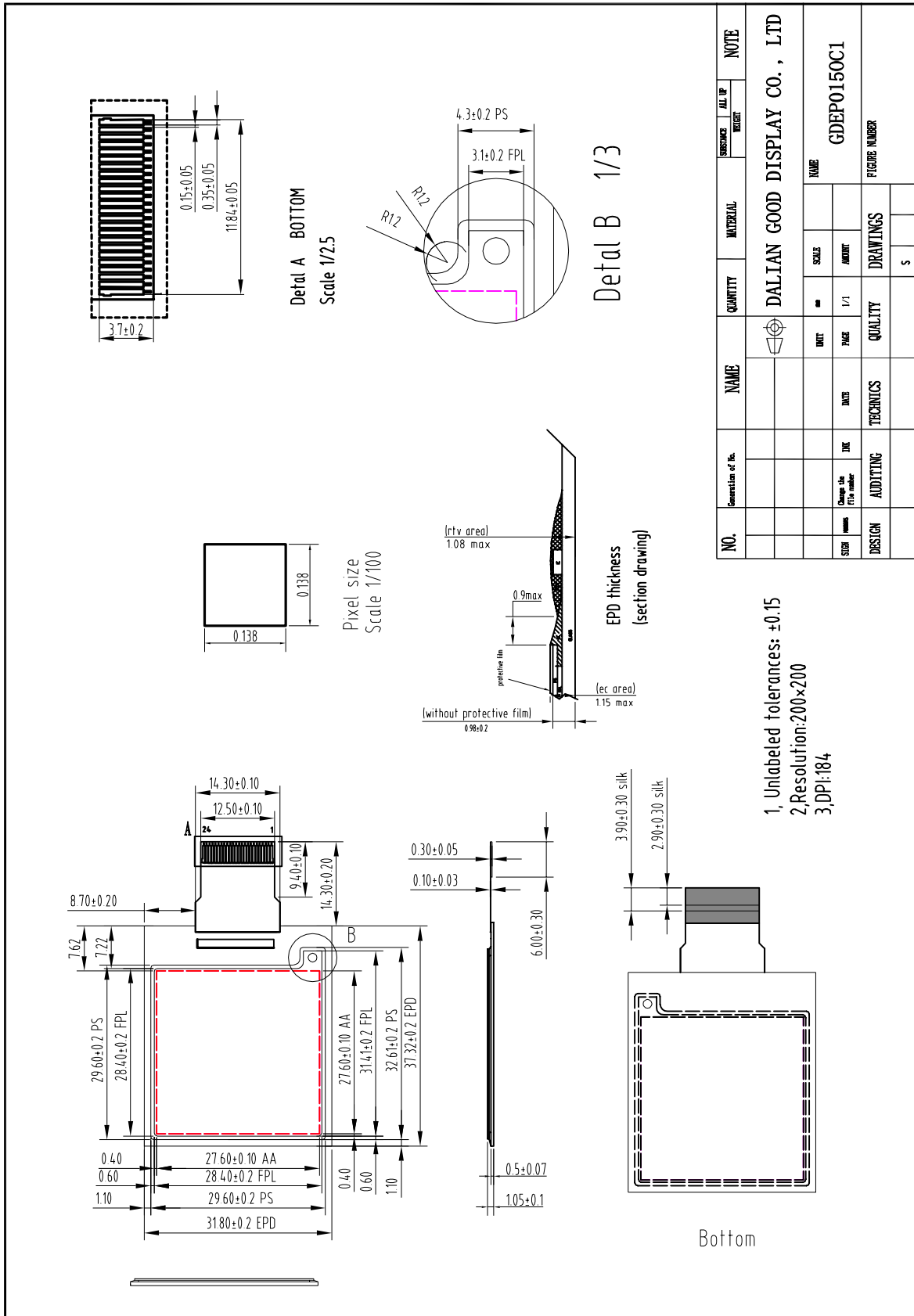
2. Features

- High contrast
- High reflectance
- Ultra wide viewing angle
- Ultra low power consumption
- Pure reflective mode
- Bi-stable
- Commercial temperature range
- Landscape, portrait mode
- Antiglare hard-coated front-surface
- Low current deep sleep mode
- On chip display RAM
- Waveform stored in On-chip OTP
- Serial peripheral interface available
- On-chip oscillator
- On-chip booster and regulator control for generating VCOM, Gate and source driving voltage.
- Available in COG package IC thickness 300um

3. Mechanical Specifications

Parameter	Specifications	Unit	Remark
Screen Size	1.54	Inch	
Display Resolution	200(H)×200(V)	Pixel	DPI: 184
Active Area	27.6(H)×27.6(V)	mm	
Pixel Pitch	0.138×0.138	mm	
Pixel Configuration	Square		
Outline Dimension	31.8(H)×37.32(V) ×1.05(D)	mm	
Weight	4±0.5	g	

4. Mechanical Drawing of EPD module





5. Input/Output Terminals

Pin #	Type	Single	Description	Remark
1		NC	No connection and do not connect with other NC pins	Keep Open
2	O	GDR	N-Channel MOSFET Gate Drive Control	
3	O	RESE	Current Sense Input for the Control Loop	
4	C	VGL	Negative Gate driving voltage	
5	C	VGH	Positive Gate driving voltage	
6		NC	Keep Open	
7		NC	Keep Open	
8	I	BS1	Bus selection pin	Note 5-5
9	O	BUSY	Busy state output pin	Note 5-4
10	I	RES #	Reset	Note 5-3
11	I	D/C #	Data /Command control pin	Note 5-2
12	I	CS #	Chip Select input pin	Note 5-1
13	I/O	D0	serial clock pin (SPI)	
14	I/O	D1	serial data pin (SPI)	
15	I	VDDIO	Power for interface logic pins	
16	I	VCI	Power Supply pin for the chip	
17		VSS	Ground	
18	C	VDD	Core logic power pin	
19	C	VPP	Power Supply for OTP Programming	
20	C	VSH	Positive Source driving voltage	
21	C	PREVGH	Power Supply pin for VGH and VSH	
22	C	VSL	Negative Source driving voltage	
23	C	PREVGL	Power Supply pin for VCOM, VGL and VSL	
24	C	VCOM	VCOM driving voltage	

Note 5-1: This pin (CS#) is the chip select input connecting to the MCU. The chip is enabled for MCU communication only when CS# is pulled Low.

Note 5-2: This pin (D/C#) is Data/Command control pin connecting to the MCU. When the pin is pulled HIGH, the data will be interpreted as data. When the pin is pulled Low, the data will be interpreted as



command.

Note 5-3: This pin (RES#) is reset signal input. The Reset is active Low.

Note 5-4: This pin (BUSY) is Busy state output pin. When Busy is High, the operation of chip should not be interrupted and any commands should not be issued to the module. The driver IC will put Busy pin High when the driver IC is working such as:

- Outputting display waveform; or
- Programming with OTP

Note 5-5: This pin (BS1) is for 3-line SPI or 4-line SPI selection. When it is “Low”, 4-line SPI is selected. When it is “High”, 3-line SPI (9 bits SPI) is selected. Please refer to below Table.

Table: Bus interface selection

BS1	MPU Interface
L	4-lines serial peripheral interface (SPI)
H	3-lines serial peripheral interface (SPI) – 9 bits SPI



6. Command Table

Command Table											Command	Description
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0		
0	0	01	0	0	0	0	0	0	0	1	Driver Output control	Gate setting
0	1		A7	A6	A5	A4	A3	A2	A1	A0		A[8:0]: MUX setting as A[8:0] + 1 POR = 12Bh + 1 MUX
0	1		0	0	0	0	0	0	0	A8		
0	1		0	0	0	0	0	B2	B1	B0		B[2]: GD Selects the 1st output Gate GD=0 [POR], G0 is the 1st gate output channel, gate output sequence is G0,G1, G2, G3, ... GD=1, G1 is the 1st gate output channel, gate output sequence is G1, G0, G3, G2, ... B[1]: SM Change scanning order of gate driver. SM=0 [POR], G0, G1, G2, G3...G299 (left and right gate interlaced) SM=1, G0, G2, G4 ...G178, G1, G3, ...G299 B[0]: TB TB = 0 [POR], scan from G0 to G299 TB = 1, scan from G299 to G0.
0	0	0C	0	0	0	0	1	1	0	0	Booster Soft start Control	Booster Enable with Phase 1, Phase 2 and Phase 3 for soft start current setting.
0	1		1	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀		
0	1		1	B ₆	B ₅	B ₄	B ₃	B ₂	B ₁	B ₀		
0	1		1	C ₆	C ₅	C ₄	C ₃	C ₂	C ₁	C ₀		A[7:0] -> Soft start setting for Phase1 = 87h [POR] B[7:0] -> Soft start setting for Phase2 = 86h [POR] C[7:0] -> Soft start setting for Phase3 = 85h [POR]
0	0	0F	0	0	0	0	1	1	1	1	Gate scan start position	Set the scanning start position of the gate driver. The valid range is from 0 to 299.
0	1		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀		
0	1		0	0	0	0	0	0	0	A ₈		When TB=0: SCN [8:0] = A[8:0] A[8:0] = 000h [POR] When TB=1: SCN [8:0] = 299 - A[8:0] A[8:0] = 000h [POR]



R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description		
0	0	10	0	0	0	1	0	0	0	0	Deep Sleep mode	Deep Sleep mode Control		
0	1		0	0	0	0	0	0	0	A ₀			A[0] :	Description
													0	Normal Mode [POR]
													1	Enter Deep Sleep Mode
0	0	11	0	0	0	1	0	0	0	1	Data Entry mode setting	Define data entry sequence A [1:0] = ID[1:0] Address automatic increment / decrement setting The setting of incrementing or decrementing of the address counter can be made independently in each upper and lower bit of the address. 00 –Y decrement, X decrement, 01 –Y decrement, X increment, 10 –Y increment, X decrement, 11 –Y increment, X increment [POR] A[2] = AM Set the direction in which the address counter is updated automatically after data are written to the RAM. AM= 0, the address counter is updated in the X direction. [POR] AM = 1, the address counter is updated in the Y direction.		
0	1		0	0	0	0	0	A ₂	A ₁	A ₀				
0	0	12	0	0	0	1	0	0	1	0	SWRESET	It resets the commands and parameters to their S/W Reset default values except R10h-Deep Sleep Mode Note: RAM are unaffected by this command.		
0	0	1A	0	0	0	1	1	0	1	0	Temperature Sensor Control (Write to temperature register)	Write to temperature register. A[7:0] – MSByte 01111111[POR] B[7:0] – LSByte 11110000[POR]		
0	1		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀				
0	1		B ₇	B ₆	B ₅	B ₄	0	0	0	0				
0	0	20	0	0	1	0	0	0	0	0	Master Activation	Activate Display Update Sequence The Display Update Sequence Option is located at R22h User should not interrupt this operation to avoid corruption of panel images.		



R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description																		
0	0	21	0	0	1	0	0	0	0	1	Display Update Control 1	<p>Option for Display Update Bypass Option used for Pattern Display, which is used for display the RAM content into the Display</p> <p>OLD RAM Bypass option A [7] A[7] = 1: Enable bypass A[7] = 0: Disable bypass [POR]</p> <p>A[4] value will be used as for bypass. A[4] = 0 [POR]</p> <p>A[1:0] Initial Update Option - Source Control</p> <table border="1"> <tr> <td>A[1:0]</td> <td>GSC</td> <td>GSD</td> </tr> <tr> <td>01 [POR]</td> <td>GS0</td> <td>GS1</td> </tr> </table>	A[1:0]	GSC	GSD	01 [POR]	GS0	GS1												
A[1:0]	GSC	GSD																												
01 [POR]	GS0	GS1																												
0	1		A ₇	0	0	A ₄	A ₃	A ₂	A ₁	A ₀																				
0	0	22	0	0	1	0	0	0	1	0	Display Update Control 2	<p>Display Update Sequence Option: Enable the stage for Master Activation</p> <table border="1"> <thead> <tr> <th></th> <th>Parameter (in Hex)</th> </tr> </thead> <tbody> <tr> <td>Enable Clock Signal, Then Enable CP Then Load Temperature value Then Load LUT Then INITIAL DISPLAY Then PATTERN DISPLAY Then Disable CP Then Disable OSC</td> <td>FF [POR]</td> </tr> <tr> <td>To Enable Clock Signal (CLKEN=1)</td> <td>80</td> </tr> <tr> <td>To Enable Clock Signal, then Enable CP (CLKEN=1, CPEN=1)</td> <td>C0</td> </tr> <tr> <td>To INITIAL DISPLAY + PATTEN DISPLAY</td> <td>0C</td> </tr> <tr> <td>To INITIAL DISPLAY</td> <td>08</td> </tr> <tr> <td>To DISPLAY PATTEN</td> <td>04</td> </tr> <tr> <td>To Disable CP, then Disable Clock Signal (CLKEN=1, CPEN=1)</td> <td>03</td> </tr> <tr> <td>To Disable Clock Signal (CLKEN=1)</td> <td>01</td> </tr> </tbody> </table> <p>Remark: CLKEN=1: If CLS=VDDIO then Enable OSC If CLS=VSS then Enable External Clock CLKEN=0: If CLS=VDDIO then Disable OSC AND INTERNAL CLOCK Signal = VSS,</p>		Parameter (in Hex)	Enable Clock Signal, Then Enable CP Then Load Temperature value Then Load LUT Then INITIAL DISPLAY Then PATTERN DISPLAY Then Disable CP Then Disable OSC	FF [POR]	To Enable Clock Signal (CLKEN=1)	80	To Enable Clock Signal, then Enable CP (CLKEN=1, CPEN=1)	C0	To INITIAL DISPLAY + PATTEN DISPLAY	0C	To INITIAL DISPLAY	08	To DISPLAY PATTEN	04	To Disable CP, then Disable Clock Signal (CLKEN=1, CPEN=1)	03	To Disable Clock Signal (CLKEN=1)	01
	Parameter (in Hex)																													
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0	1		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀																				



R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description																
0	0	24	0	0	1	0	0	1	0	0	Write RAM	After this command, data entries will be written into the RAM until another command is written. Address pointers will advance accordingly.																
0	0	2C	0	0	1	0	1	0	1	1	Write VCOM register	Write VCOM register from MCU interface																
0	1		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀																		
0	0	32	0	0	1	1	0	0	1	0	Write LUT register	Write LUT register from MCU [240 bits], (excluding the VSH/VSL and Dummy bit)																
0	1		LUT [30 bytes]																									
0	1																											
0	1																											
0	1																											
0	0	3A	0	0	1	1	1	0	1	0	Set dummy line period	Set number of dummy line period A[6:0]: Number of dummy line period in term of TGate A[6:0] = 16h [POR] Available setting 0 to 127.																
0	1		0	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀																		
0	0	3C	0	0	1	1	1	1	0	0	Border Waveform Control	Select border waveform for VBD A [7] Follow Source at Initial Update Display A [7]=0: [POR] A [7]=1: Follow Source at Initial Update Display for VBD, A [6:0] setting are being overridden at Initial Display STAGE. A [6] Select GS Transition/ Fix Level for VBD A [6]=0: Select GS Transition A[3:0] for VBD A [6]=1: Select FIX level Setting A[5:4] for VBD [POR] A [5:4] Fix Level Setting for VBD <table border="1" style="margin-left: 20px;"> <tr> <td>A[5:4]</td> <td>VBD level</td> </tr> <tr> <td>00</td> <td>VSS</td> </tr> <tr> <td>01</td> <td>VSH</td> </tr> <tr> <td>10</td> <td>VSL</td> </tr> <tr> <td>11[POR]</td> <td>HiZ</td> </tr> </table> A [1:0] GS transition setting for VBD (Select waveform like data A[3:2] to data A[1:0]) <table border="1" style="margin-left: 20px;"> <tr> <td>A[1:0]</td> <td>GSA</td> <td>GSB</td> </tr> <tr> <td>01 [POR]</td> <td>GS0</td> <td>GS1</td> </tr> </table>	A[5:4]	VBD level	00	VSS	01	VSH	10	VSL	11[POR]	HiZ	A[1:0]	GSA	GSB	01 [POR]	GS0	GS1
A[5:4]	VBD level																											
00	VSS																											
01	VSH																											
10	VSL																											
11[POR]	HiZ																											
A[1:0]	GSA	GSB																										
01 [POR]	GS0	GS1																										
0	1		A ₇	A ₆	A ₅	A ₄	0	0	A ₁	A ₀																		



R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
0	0	44	0	1	0	0	0	1	0	0	Set RAM X - address Start / End position	Specify the start/end positions of the window address in the X direction by an address unit A[4:0]: XSA[4:0], XStart, POR = 00h B[4:0]: XEA[4:0], XEnd, POR = 18h
0	1		0	0	0	A ₄	A ₃	A ₂	A ₁	A ₀		
0	1		0	0	0	B ₄	B ₃	B ₂	B ₁	B ₀		
0	0	45	0	1	0	0	0	1	0	1	Set Ram Y- address Start / End position	Specify the start/end positions of the window address in the Y direction by an address unit A[8:0]: YSA[8:0], YStart, POR = 000h B[8:0]: YEA[8:0], YEnd, POR = 12Bh
0	1		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀		
0	1		0	0	0	0	0	0	0	A ₈		
0	1		B ₇	B ₆	B ₅	B ₄	B ₃	B ₂	B ₁	B ₀		
0	1		0	0	0	0	0	0	0	B ₈		
0	0	4E	0	1	0	0	1	1	1	0	Set RAM X address counter	Make initial settings for the RAM X address in the address counter (AC) A[4:0]: XAD[4:0], POR is 00h
0	1		0	0	0	A ₄	A ₃	A ₂	A ₁	A ₀		
0	0	4F	0	1	0	0	1	1	1	1	Set RAM Y address counter	Make initial settings for the RAM Y address in the address counter (AC) A[8:0]: YAD8:0], POR is 000h
0	1		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀		
0	1		0	0	0	0	0	0	0	A ₈		
0	1	FF	1	1	1	1	1	1	1	1	NOP	This command is an empty command; it does not have any effect on the display module. However it can be used to terminate Frame Memory Write or Read Commands.



7. Electrical Characteristics

7-1) Absolute maximum rating

Parameter	Symbol	Rating	Unit
Logic Supply Voltage	V _{CI}	-0.5 to +3.6	V
Logic Input Voltage	V _{IN}	-0.5 to V _{CI} +0.5	V
Logic Output Voltage	V _{OUT}	-0.5 to V _{CI} +0.5	V
Operating Temp. range	T _{OPR}	0 to +50	°C
Storage Temp. range	T _{STG}	-25 to +70	°C

7-2) Panel DC Characteristics

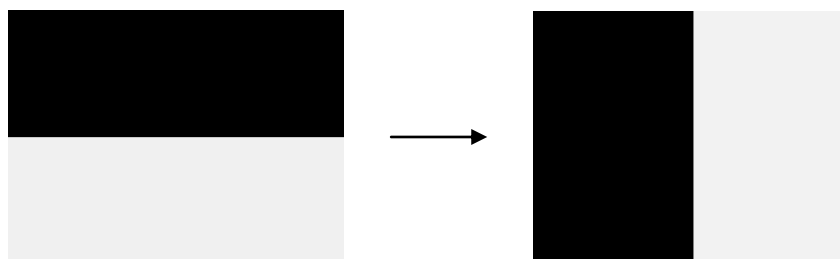
The following specifications apply for : V_{SS} = 0V, V_{CI} = 3.0V, T_A = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Single ground	V _{SS}	-	-	0	-	V
Logic Supply Voltage	V _{CI}	-	2.4	3.3	3.7	V
High level input voltage	V _{IH}	-	0.8V _{CI}	-	-	V
Low level input voltage	V _{IL}	-	-	-	0.2V _{CI}	V
High level output voltage	V _{OH}	IOH= -100uA	0.9V _{CI}	-	-	V
Low level output voltage	V _{OL}	IOH= 100uA	-	-	0.1V _{CI}	V
Image update current	I _{UPDATE}	-	-	8	10	mA
Standby panel current	I _{standby}	-	-	-	5	uA
Power panel (update)	P _{UPDATE}	-	-	26.4	-	mW
Standby power panel	P _{STBY}	-	-	-	0.0165	mW
Operating temperature	-	-	0	-	50	°C
Storage temperature	-	-	-25	-	70	°C
Image update Time at 25 °C	-	-	-	680	-	ms
Partial image update Time at 25 °C	-	-	-	280	-	ms
Deep sleep mode current	V _{CI}	DC/DC off No clock No input load Ram data not retain	-	2	5	uA
Sleep mode current	V _{CI}	DC/DC off No clock No input load Ram data retain	-	35	50	uA

- The Typical power consumption is measured with following pattern transition: from horizontal 2 gray scale pattern to vertical 2 gray scale pattern.(Note 7-1)
- The standby power is the consumed power when the panel controller is in standby mode.
- The listed electrical/optical characteristics are only guaranteed under the controller & waveform provided by Good Display.

- Vcom is recommended to be set in the range of assigned value $\pm 0.1V$.

Note 7-1: The Typical power consumption



7-3) Panel AC Characteristics

7-3-1) Oscillator frequency

The following specifications apply for : VSS = 0V, VCI = 3.0V, T_A = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Internal Oscillator frequency	Fosc	VCI=2.4 to 3.7V	0.95	1	1.05	MHz

7-3-2) MCU Interface

7-3-2-1) MCU Interface Selection

In this module, there are 4-wire SPI and 3-wire SPI that can communicate with MCU. The MCU interface mode can be set by hardware selection on BS1 pins. When it is “Low”, 4-wire SPI is selected. When it is “High”, 3-wire SPI (9 bits SPI) is selected.

Pin Name	Data/Command Interface		Control Signal		
	D1	D0	CS#	D/C#	RES#
Bus interface	SDin	SCLK	CS#	D/C#	RES#
SPI4	SDin	SCLK	CS#	L	RES#
SPI3	SDin	SCLK	CS#	L	RES#

Table 7-1: MCU interface assignment under different bus interface mode

Note 7-2: L is connected to VSS

Note 7-3: H is connected to VCI

7-3-2-2) MCU Serial Interface (4-wire SPI)

The 4-wire SPI consists of serial clock SCLK, serial data SDIN, D/C#, CS#. In SPI mode, D0 acts as SCLK, D1 acts as SDIN.

Function	CS#	D/C#	SCLK
Write Command	L	L	↑
Write data	L	H	↑

Table 7-2: Control pins of 4-wire Serial Peripheral interface

Note 7-4: ↑stands for rising edge of signal

SDIN is shifted into an 8-bit shift register in the order of D7, D6, ... D0. The data byte in the shift register is written to the Graphic Display Data RAM (RAM) or command register in the same clock. Under serial mode, only write operations are allowed.

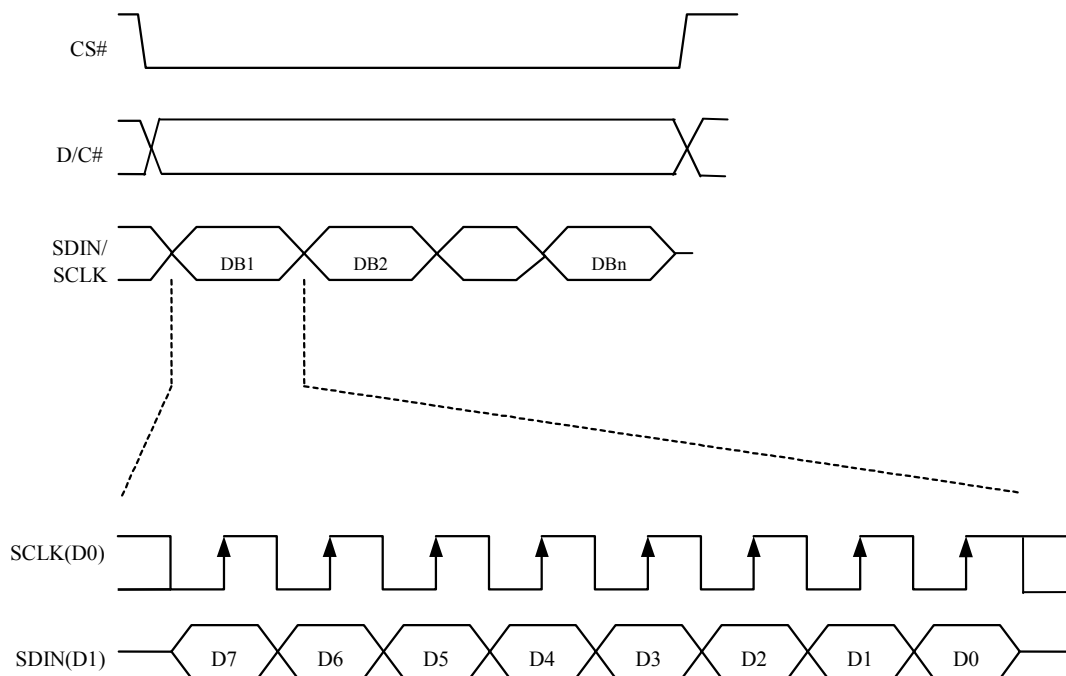


Figure 7-1: Write procedure in 4-wire Serial Peripheral Interface mode

7-3-2-3) MCU Serial Interface (3-wire SPI)

The 3-wire serial interface consists of serial clock SCLK, serial data ADIN and CS#.

In 3-wire SPI mode, D0 acts as SCLK, D1 acts as SDIN, The pin D/C# can be connected to an external ground.

The operation is similar to 4-wire serial interface while D/C# pin is not used. There are altogether 9-bits will be shifted into the shift register on every ninth clock in sequence : D/C# bit, D7 to D0 bit. The D/C# bit (first bit of the sequential data) will determine the following data byte in shift register is written to the Display Data RAM (D/C# bit = 1) or the command register (D/C# bit = 0). Under serial mode ,only write operations are allowed.

Function	CS#	D/C#	SCLK
Write Command	L	Tie LOW	↑
Write data	L	Tie LOW	↑

Table 7-3: Control pins of 3-wire Serial Peripheral Interface

Note 7-5: ↑stands for rising edge of signal

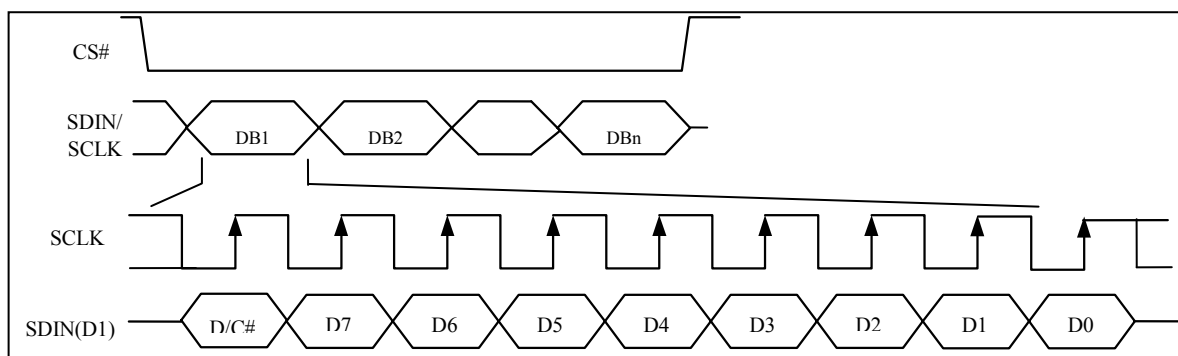


Figure 7-2: Write procedure in 3-wire Serial Peripheral Interface mode

7-3-3) Timing Characteristics of Series Interface

(VCI - VSS = 1.8 V to 2.0 v , T_A = 25 °C , C_L = 20 pF)

Symbol	Parameter	Min	Typ	Max	Unit
t _{cycle}	Clock Cycle Time	250	-	-	ns
t _{AS}	Address Setup Time	150	-	-	ns
t _{AH}	Address Hold Time	150	-	-	ns
t _{CSS}	Chip Select Setup Time	120	-	-	ns
t _{CSH}	Chip Select Hold Time	60	-	-	ns
t _{DSW}	Write Data Setup Time	50	-	-	ns
t _{DHW}	Write Data Hold Time	15	-	-	ns
t _{CLKL}	Clock Low Time	100	-	-	ns
t _{CLKH}	Clock High Time	100	-	-	ns
t _R	Rise Time [20%~80%]	-	-	15	ns
t _F	Fall Time [20%~80%]	-	-	15	ns

Table 7-4: Serial Peripheral Interface Timing Characteristics

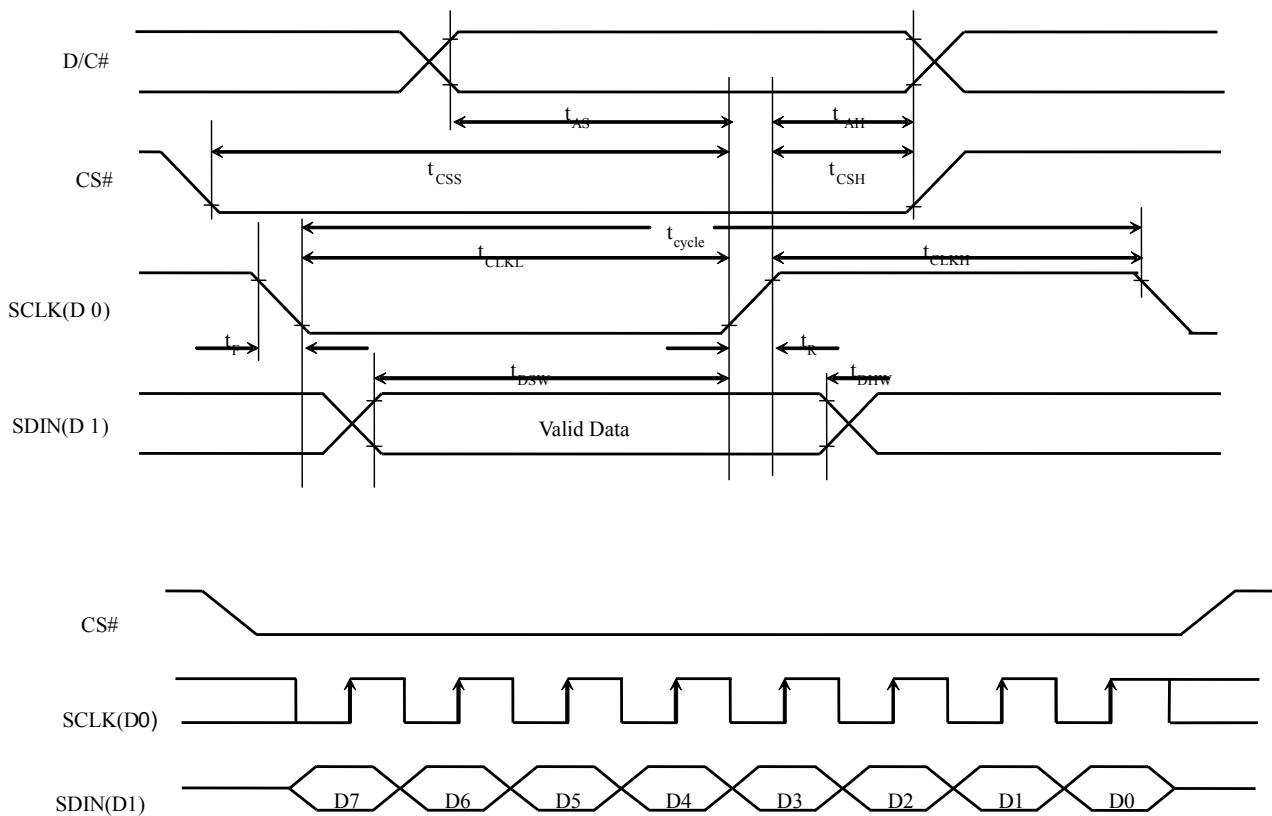
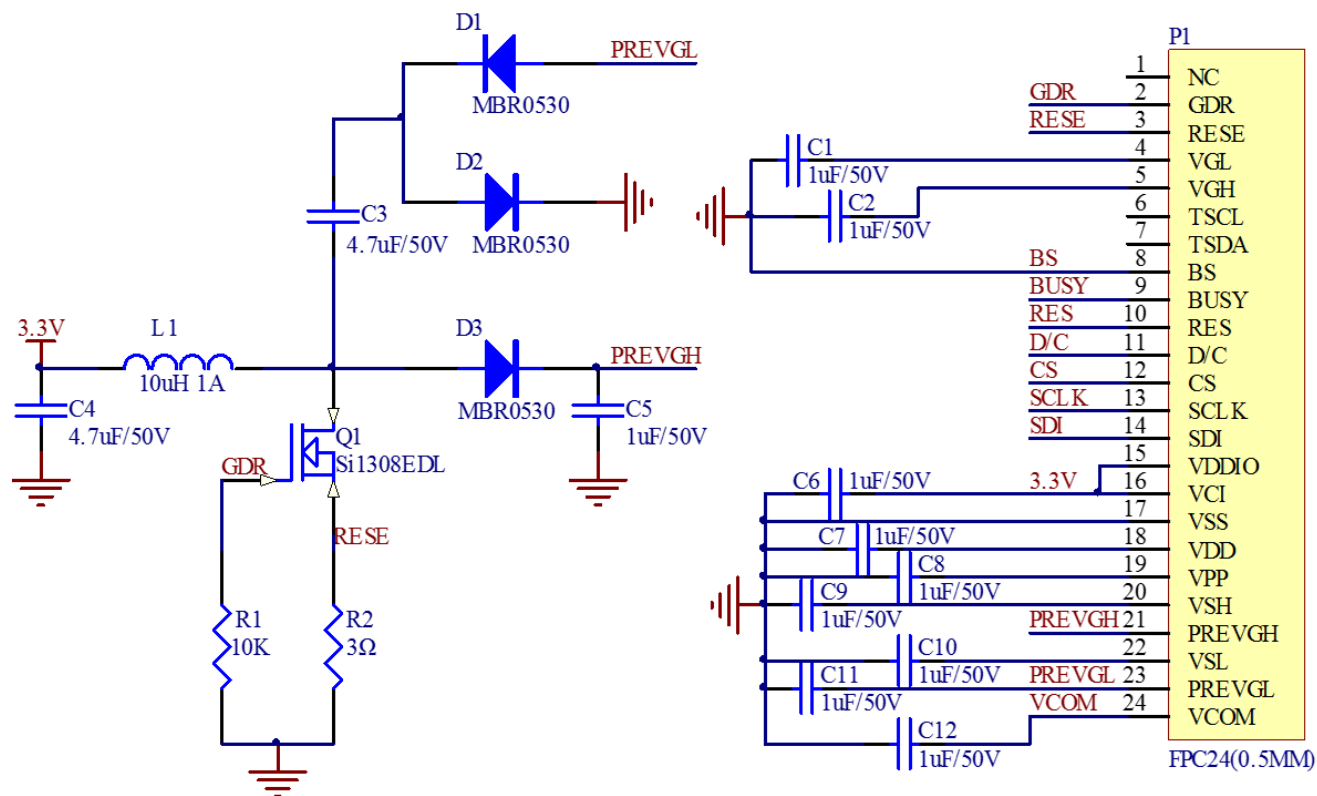


Figure 7-3 : Serial peripheral interface characteristics

7-4) Power Consumption

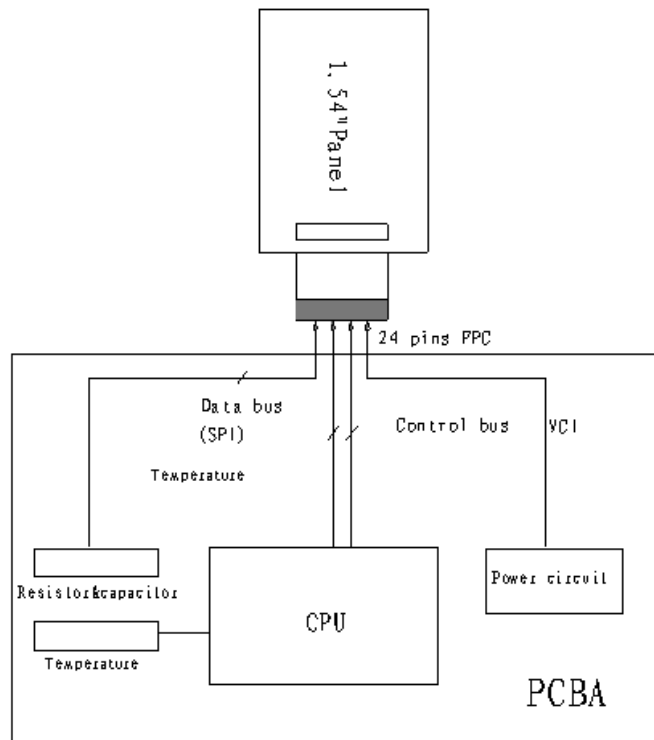
Parameter	Symbol	Conditions	TYP	Max	Unit	Remark
Panel power consumption during update	-	-	26.4	40	mW	-
Power consumption in standby mode	-	-	-	0.017	mW	-

7-5) Reference Circuit


Note :

1. Inductor L1 is wire-wound inductor. There are no special requirements for other parameters.
2. Suggests using Si1304BDL or Si1308EDL TUBE MOS (Q1) , otherwise it may affect the normal boost of the circuit.
3. The default circuit is 4-wire SPI. If the user wants to use 3-wire SPI, the resistor R4 can be removed when users design.
4. Default voltage value of all capacitors is 50V.

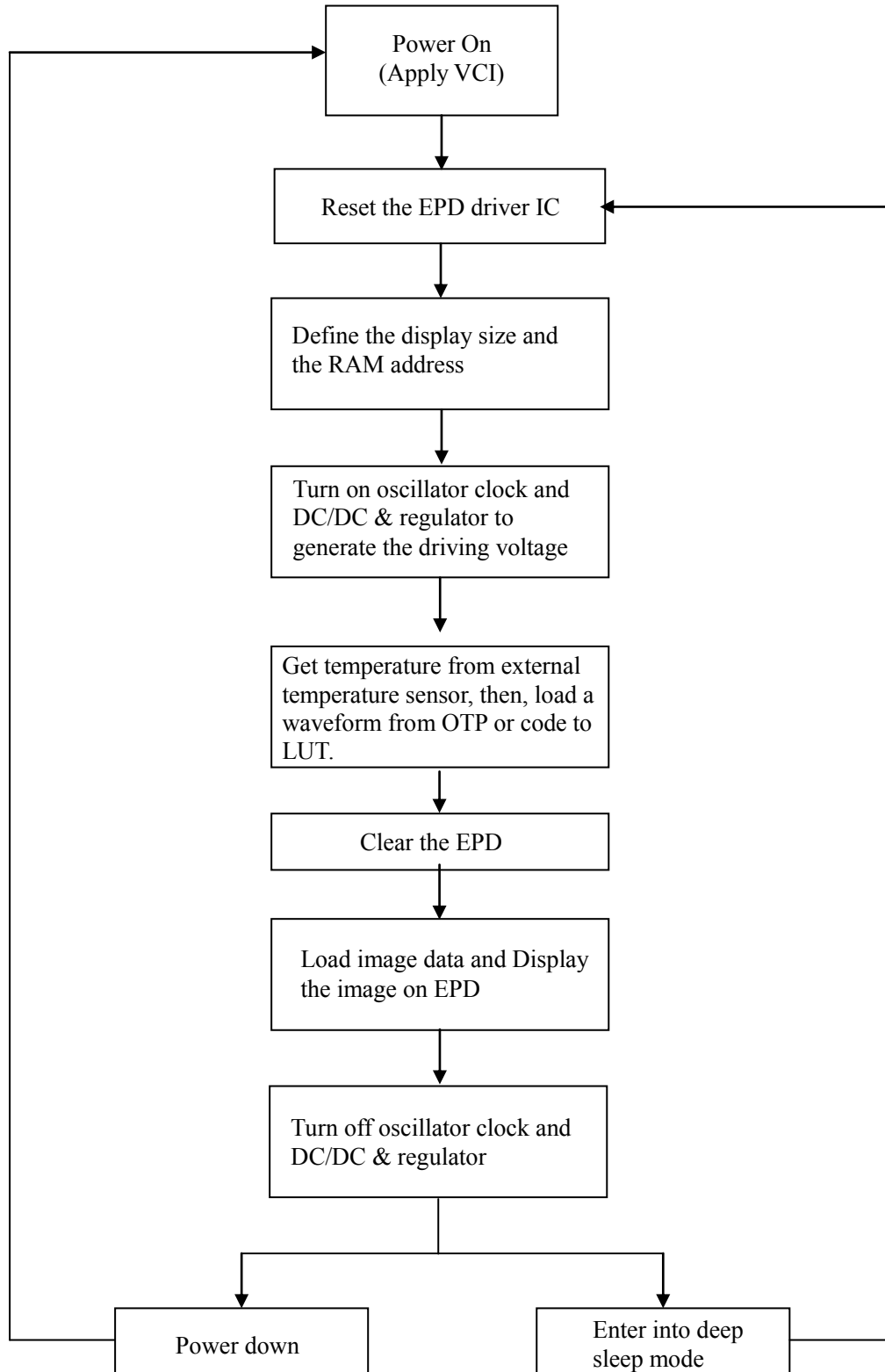
7-6) Block Diagram





8. Typical Operating Sequence

Normal Operation Flow



9. Optical characteristics

9-1) Specifications

Measurements are made with that the illumination is under an angle of 45 degrees, the detection is perpendicular unless otherwise specified.

T=25°C

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT	Note
R	Reflectance	White	30	35	-	%	Note 9-1
Gn	2Grey Level	-	-	$DS+(WS-DS) \times n^{(m-1)}$	-	L*	-
CR	Contrast Ratio	indoor	8		-	-	-
Panel's life		0°C~50°C		1000000 times or 5 years			Note 9-2

WS : White state, DS : Dark state

Gray state from Dark to White : DS、 WS

m : 2

Note 9-1 : Luminance meter : Eye – One Pro Spectrophotometer

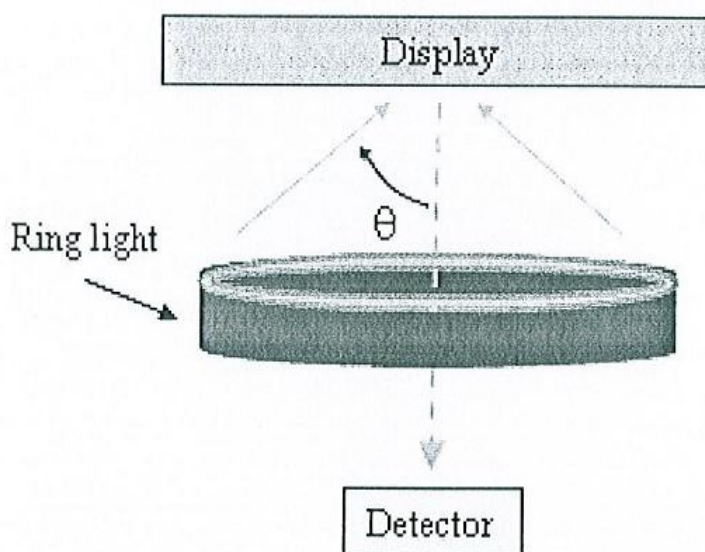
Note 9-2 : When work in temperature below 0 degree or above 50 degree , we do not recommend because the panel's life will not be guaranteed

9-2) Definition of contrast ratio

The contrast ratio (CR) is the ratio between the reflectance in a full white area (R1) and the reflectance in a dark area (Rd)():

R1: white reflectance Rd: dark reflectance

$$CR = R1/Rd$$

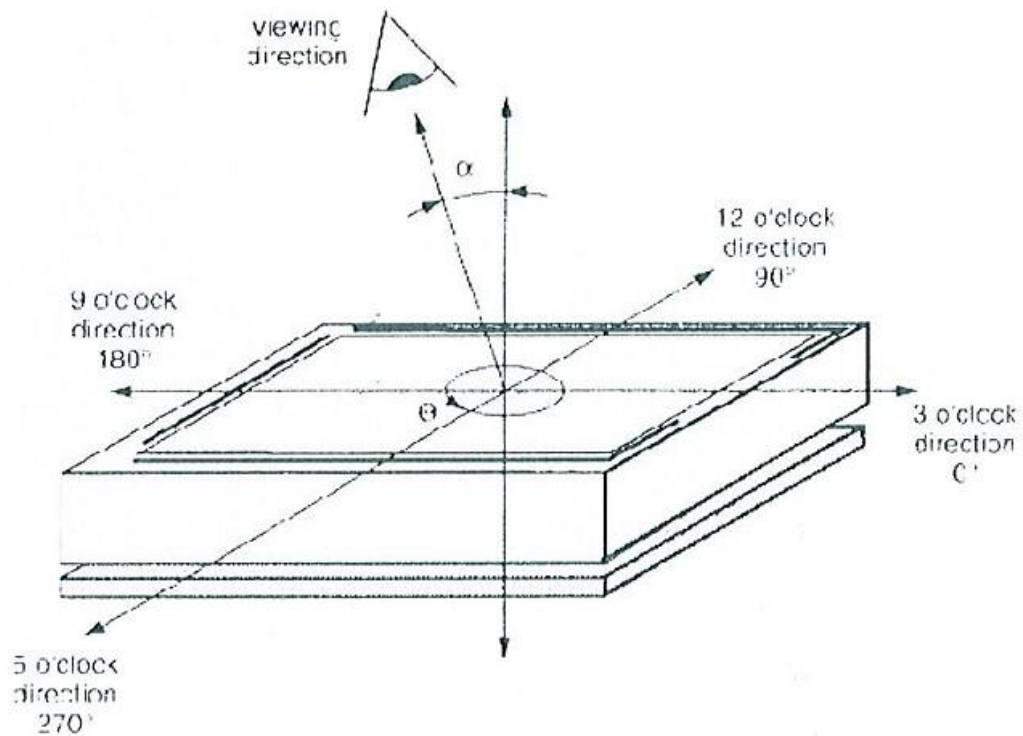


9-3) Reflection Ratio

The reflection ratio is expressed as :

$$R = \text{Reflectance Factor}_{\text{white board}} \times (L_{\text{center}} / L_{\text{white board}})$$

L_{center} is the luminance measured at center in a white area ($R=G=B=1$). $L_{\text{white board}}$ is the luminance of a standard white board. Both are measured with equivalent illumination source. The viewing angle shall be no more than 2 degrees.





10. HANDLING, SAFETY AND ENVIROMENTAL REQUIREMENTS

WARNING

The display glass may break when it is dropped or bumped on a hard surface . Handle with care.
Should the display break, do not touch the electrophoretic material . In case of contact with electrophoretic material , wash with water and soap.

CAUTION

The display module should not be exposed to harmful gases , such as acid and alkali gases , which corrode electronic components.

Disassembling the display module can cause permanent damage and invalidate the warranty agreements.

Observe general precautions that are common to handling delicate electronic components . The glass can break and front surfaces can easily be damaged . Moreover the display is sensitive to static electricity and other rough environmental conditions.

Data sheet status

Product specification	The data sheet contains final product specifications.
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Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134).

Stress above one or more of the limiting values may cause permanent damage to the device.

These are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of the specification is not implied . Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given , it is advisory and dose not form part of the specification.

Product Environmental certification

ROHS

**11. Reliability test**

	TEST ITEMS	CONDITION	METHOD	REMARK
1	High-Temperature Operation	T = 50°C,30% for 240 hrs	IEC 60 068-2-2Bp	
2	Low-Temperature Operation	T = 0°C for 240 hrs	IEC 60 068-2-2Ab	
3	High-Temperature Storage	T = +70°C, 23% for 240 hrs Test in white pattern	IEC 60 068-2-2Bp	
4	Low-Temperature Storage	T = -25°C for 240 hrs Test in white pattern	IEC 60 068-2-2Ab	
5	High Temperature, High-Humidity Operation	T=+40°C,RH=90%for168hrs	IEC 60 068-2-3CA	
6	High Temperature, High-Humidity Storage	T=+60°C,RH=80%for240hrs Test in white pattern	IEC 60 068-2-3CA	
7	Temperature Cycle	[-25°C 30mins]→ [+70°C 30mins] ,70cycles Test in white pattern	IEC 60 068-2-14NB	
8	UV exposure Resistance	765 W/m ² for 168 hrs,40°C	IEC 60 068-2-5 Sa	
9	Electrostatic discharge	Air-mode:+/-8kV, Contact-mode:+/-6kV, 330 Ω ,150pF	IEC61000-4-2	
10	Package Vibration	1.04G,Frequency : 10~500Hz Direction : X,Y,Z Duration:1hours in each direction	Full packed for shipment	
11	Package Drop Impact	Drop from height of 122 cm on Concrete surface Drop sequence:1 corner, 3edges, 6face One drop for each.	Full packed for shipment	
12	Altitude test Operation	700hPa (=3000 m),48Hr		
13	Altitude test Storage	260hPa (=10000 m),48Hr Test in white pattern		
14	Stylus Tapping	POLYACETAL Pen: Top R:0.8mm Load: 300gf Speed: 30times/min Total 13,500times,	Test should be done with a bezel	Pass criteria – no glass breakage or damage to microcapsules

Actual EMC level to be measured on customer application.

Note : The protective film must be removed before temperature test.

12. Packing

